WHAT IS CLAIMED IS:

5

10

1. An electron-emitting device, comprising:

a cathode electrode and a gate electrode, which are formed on a surface of a substrate and opposed to each other with a space therebetween; and

a film containing an electron-emitting material, which is located on the cathode electrode,

wherein the film containing the electronemitting material has two end portions in a plane
substantially parallel to the surface in a direction
substantially perpendicular to a direction along
which the cathode electrode and the gate electrode
are opposed to each other,

wherein a structure is used in which electric

field strengths applied between each of the two end
portions of the film containing the electron-emitting
material and the gate electrode are made weaker than
an electric field strength applied between a region
between the two end portions of the film containing

the electron-emitting material and the gate electrode
at a time of driving.

- 2. An electron-emitting device, comprising:
- a cathode electrode and a gate electrode, which
- 25 are formed on a surface of a substrate and opposed to each other with a space therebetween; and
 - a film containing an electron-emitting material,

which is located on the cathode electrode,

10

15

wherein the film containing the electronemitting material has two end portions in a plane
substantially parallel to the surface of the
substrate in a direction substantially perpendicular
to a direction along which the cathode electrode and
the gate electrode are opposed to each other,

wherein an area of a portion of the cathode electrode between each of the two end portions of the film containing the electron-emitting material and the gate electrode in the plane substantially parallel to the surface of the substrate is larger than an area of a portion of the cathode electrode between a region located between the two end portions of the film containing the electron-emitting material and the gate electrode.

- 3. An electron-emitting device, comprising:
- a cathode electrode and a gate electrode, which
 are formed on a surface of a substrate and opposed to
 each other with a space therebetween; and
 - a film containing an electron-emitting material, which is located on the cathode electrode,

wherein the film containing the electron25 emitting material has two end portions in a plane
substantially parallel to the surface of the
substrate in a direction substantially perpendicular

to a direction along which the cathode electrode and the gate electrode are opposed to each other,

wherein the cathode electrode has protruding portions in areas between each of the two end

5 portions of the film containing the electron-emitting material and the gate electrode in a plane substantially parallel to the surface of the substrate, the protruding portions protruding more to the gate electrode side as compared with an area

10 between a region located between the two end portions of the film containing the electron-emitting material and the gate electrode.

4. An electron-emitting device, comprising:

a cathode electrode and a gate electrode, which are formed on a surface of a substrate and opposed to each other with a space therebetween; and

15

a film containing an electron-emitting material, which is located on the cathode electrode,

wherein the film containing the electronemitting material has two end portions in a plane
substantially parallel to the surface of the
substrate in a direction substantially perpendicular
to a direction along which the cathode electrode and
the gate electrode are opposed to each other,

wherein the gate electrode has a shape in which a distance therefrom to a region located between the

two end portions of the film containing the electronemitting material is shorter than a distance therefrom to each of the two end portions of the film containing the electron-emitting material.

5

10

15

20

5. An electron-emitting device, comprising:

a cathode electrode and a gate electrode, which are formed on a surface of a substrate and opposed to each other with a space therebetween; and

a film containing an electron-emitting material, which is located on the cathode electrode,

wherein the film containing the electronemitting material has two end portions in a plane
substantially parallel to the surface of the
substrate in a direction substantially perpendicular
to a direction along which the cathode electrode and
the gate electrode are opposed to each other,

wherein a distance from a center line between the cathode electrode and the gate electrode to a region located between the two end portions of the film containing the electron-emitting material is shorter than a distance from the center line to each of the two end portions of the film containing the electron-emitting material.

25

6. An electron-emitting device according to claim 1, wherein the film containing the electron-

emitting material comprises a plurality of fibrous conductive materials.

- 7. An electron-emitting device according to claim 1, wherein the film containing the electron-emitting material contains mainly carbon.
- 8. An electron-emitting device according to claim 1, wherein the film containing the electronemitting material comprises a plurality of carbon fibers.
- 9. An electron-emitting device according to claim 8, wherein each of the plurality of carbon
 15 fibers includes at least one of a carbon nanotube, a graphite nanofiber, an amorphous carbon fiber, and a diamond fiber.
 - 10. An electron source, comprising:
- a plurality of electron-emitting devices, each of which is constructed according to any one of claims 1.
- 11. An image display apparatus, comprising:
 25 an electron source constructed according to claim 10; and
 - a light emitting member.